



APTD2012F3C
2.0 x 1.25 mm Infrared Emitting Diode

DESCRIPTION

- F3 Made with Gallium Arsenide Infrared Emitting diodes

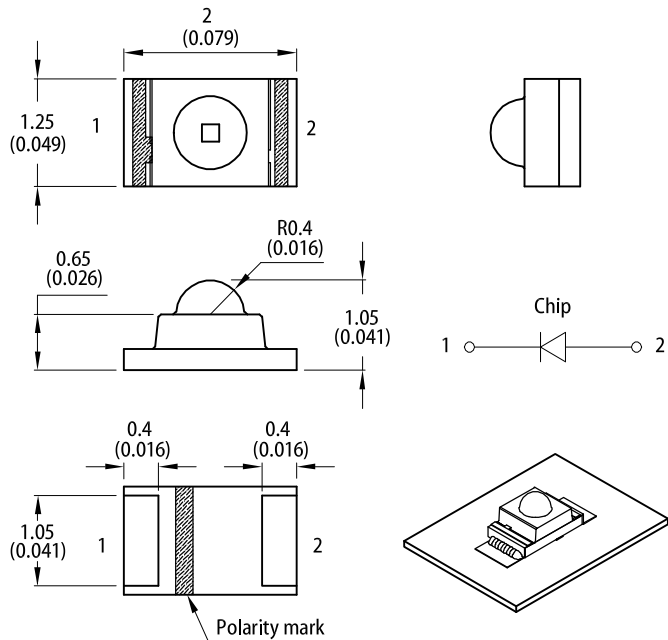
FEATURES

- 2.0 mm x 1.25 mm SMD LED, 1.05 mm thickness
- Low power consumption
- Mechanically and spectrally matched to the Phototransistor
- Package matches with photodetector APT2012P3BT
- Package: 3000 pcs / reel
- Moisture sensitivity level: 3
- Halogen-free
- RoHS compliant

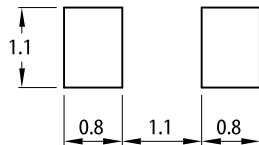
APPLICATIONS

- Infrared Illumination for cameras
- Machine vision systems
- Surveillance systems
- Industrial electronics
- IR data transmission
- Remote control

PACKAGE DIMENSIONS



RECOMMENDED SOLDERING PATTERN
(units : mm; tolerance : ± 0.1)



- Notes:
1. $\theta_{1/2}$ is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value.
 2. Tolerance is $\pm 0.15(0.006")$ unless otherwise noted.
 3. The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.
 4. The device has a single mounting surface. The device must be mounted according to the specifications.

SELECTION GUIDE

Part Number	Emitting Color (Material)	Lens Type	Po (mW/sr) @ 20mA ^[2]		Viewing Angle ^[1]
			Min.	Typ.	2 $\theta_{1/2}$
APTD2012F3C	Infrared (GaAs)	Water Clear	2	5	40°
			*1.2	*3	

Notes:
1. $\theta_{1/2}$ is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value.
2. Radiant Intensity / luminous flux: +/-15%.
* Radiant intensity value is traceable to CIE127-2007 standards.

ELECTRICAL / OPTICAL CHARACTERISTICS at T_A=25°C

Parameter	Symbol	Emitting Color	Value		Unit
			Typ.	Max.	
Wavelength at Peak Emission I _F = 20mA	λ _{peak}	Infrared	940	-	nm
Spectral Bandwidth at 50% Φ REL MAX I _F = 20mA	Δλ	Infrared	50	-	nm
Forward Voltage I _F = 20mA	V _F ^[1]	Infrared	1.2	1.6	V
Reverse Current (V _R = 5V)	I _R	Infrared	-	10	μA
Temperature Coefficient of Wavelength I _F = 20mA, -10°C ≤ T ≤ 85°C	TC _λ	Infrared	0.3	-	nm/°C
Temperature Coefficient of V _F I _F = 20mA, -10°C ≤ T ≤ 85°C	TC _V	Infrared	-1.2	-	mV/°C

Notes:
1. Forward voltage: ±0.1V.
2. Wavelength value is traceable to CIE127-2007 standards.
3. Excess driving current and / or operating temperature higher than recommended conditions may result in severe light degradation or premature failure.

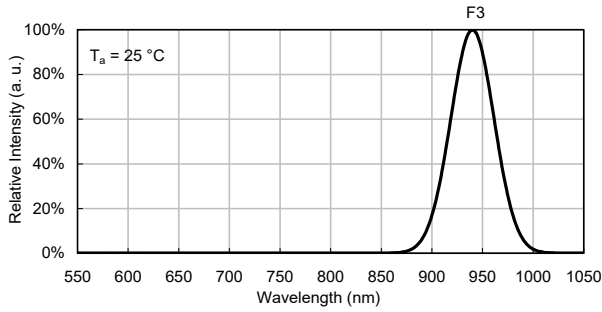
ABSOLUTE MAXIMUM RATINGS at T_A=25°C

Parameter	Symbol	Value	Unit
Power Dissipation	P _D	90	mW
Reverse Voltage	V _R	5	V
Junction Temperature	T _j	115	°C
Operating Temperature	T _{op}	-40 to +85	°C
Storage Temperature	T _{stg}	-40 to +85	°C
DC Forward Current	I _F	50	mA
Peak Forward Current	I _{FP} ^[1]	1200	mA
Electrostatic Discharge Threshold (HBM)	-	8000	V
Thermal Resistance (Junction / Ambient)	R _{th JA} ^[2]	660	°C/W
Thermal Resistance (Junction / Solder point)	R _{th JS} ^[2]	530	°C/W

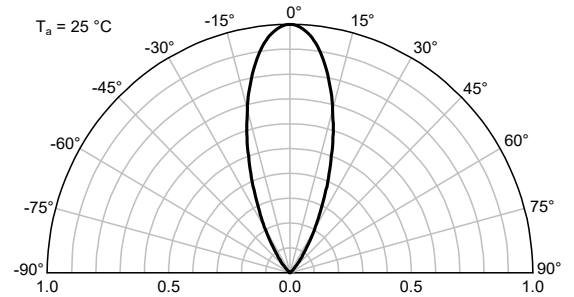
Notes:
1. 1/100 Duty Cycle, 10μs Pulse Width.
2. R_{th JA}, R_{th JS} Results from mounting on PC board FR4 (pad size ≥ 16 mm² per pad).
3. Relative humidity levels maintained between 40% and 60% in production area are recommended to avoid the build-up of static electricity – Ref JEDEC/JESD625-A and JEDEC/J-STD-033.

TECHNICAL DATA

RELATIVE INTENSITY vs. WAVELENGTH

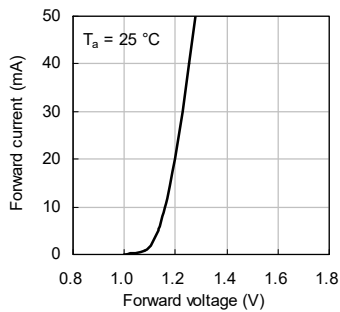


SPATIAL DISTRIBUTION

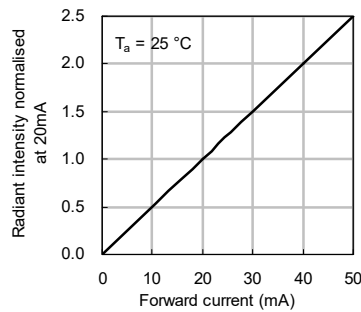


INFRARED

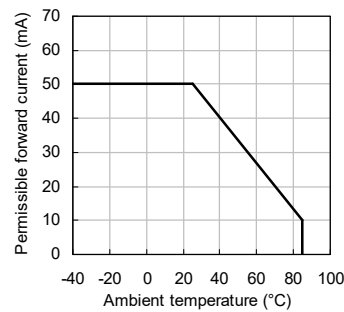
Forward Current vs. Forward Voltage



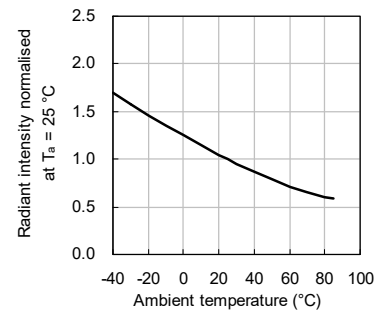
Radiant Intensity vs. Forward Current



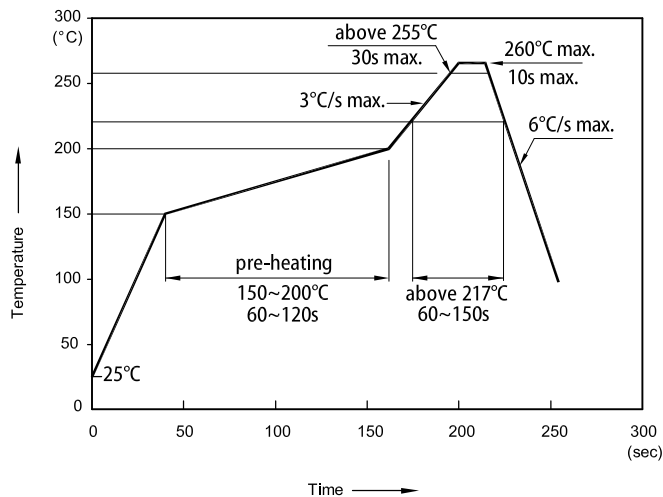
Forward Current Derating Curve



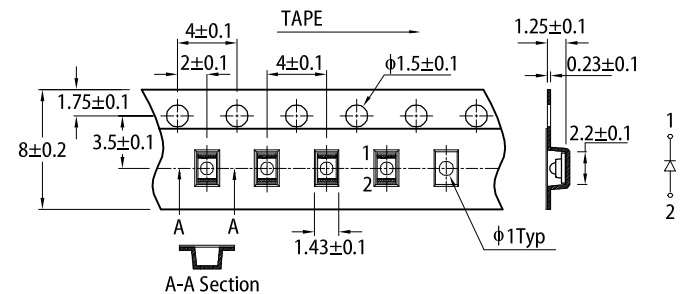
Radiant Intensity vs. Ambient Temperature



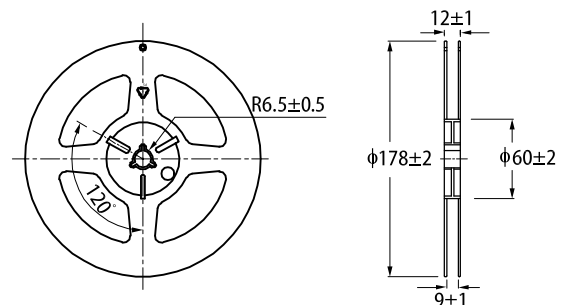
REFLOW SOLDERING PROFILE for LEAD-FREE SMD PROCESS



TAPE SPECIFICATIONS (units : mm)

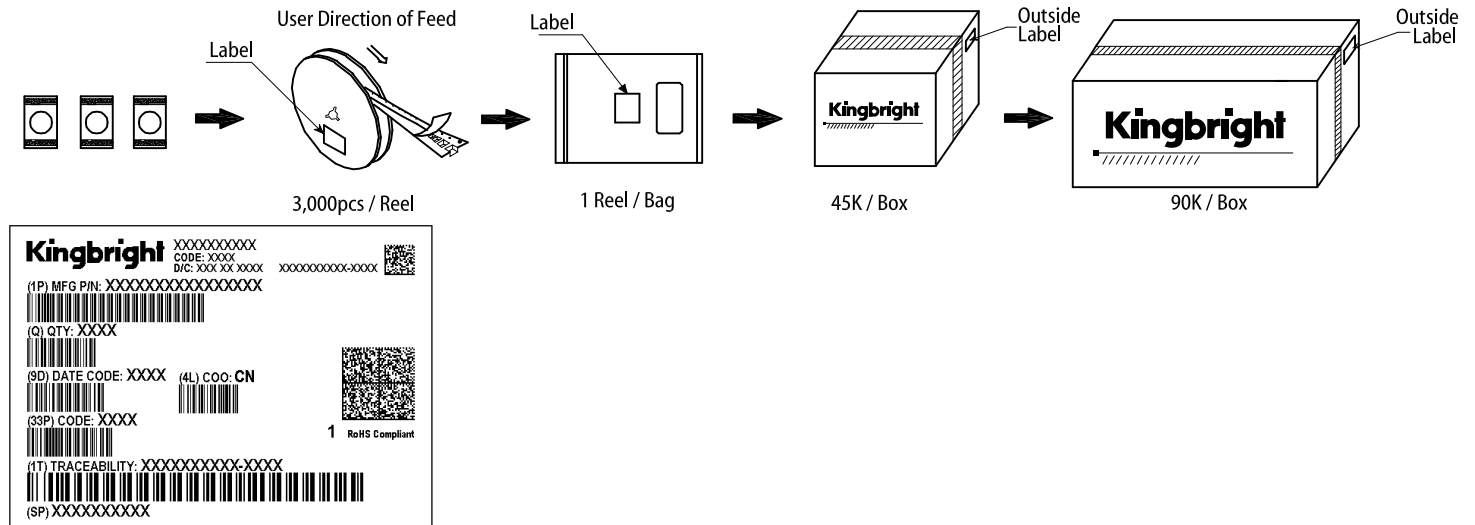


REEL DIMENSION (units : mm)



- Notes:
1. Don't cause stress to the LEDs while it is exposed to high temperature.
 2. The maximum number of reflow soldering passes is 2 times.
 3. Reflow soldering is recommended. Other soldering methods are not recommended as they might cause damage to the product.

PACKING & LABEL SPECIFICATIONS



PRECAUTIONARY NOTES

1. The information included in this document reflects representative usage scenarios and is intended for technical reference only.
2. The part number, type, and specifications mentioned in this document are subject to future change and improvement without notice. Before production usage customer should refer to the latest datasheet for the updated specifications.
3. When using the products referenced in this document, please make sure the product is being operated within the environmental and electrical limits specified in the datasheet. If customer usage exceeds the specified limits, Kingbright will not be responsible for any subsequent issues.
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